

High-speed graphene transistors with a self-aligned nan

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Citation Report

#	ARTICLE	IF	CITATIONS
2	60ÅGHz current gain cut-off frequency graphene nanoribbon FET. International Journal of Microwave and Wireless Technologies, 2010, 2, 441-444.	1.5	3
3	Chemical Functionalization of Graphene Enabled by Phage Displayed Peptides. Nano Letters, 2010, 10, 4559-4565.	4.5	190
4	Aspects of the theory of graphene. Philosophical Transactions Series A, Mathematical, Physical, and Engineering Sciences, 2010, 368, 5525-5556.	1.6	27
5	Self-consistent simulation of array-based CNFETs: Impact of tube pitch on RF performance. , 2010, , .		7
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7	Tunable transmission Gap in graphene p-n junction. , 2011, , .		0
8	Synthesis and electric properties of dicobalt silicide nanobelts. Chemical Communications, 2011, 47, 1255-1257.	2.2	15
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